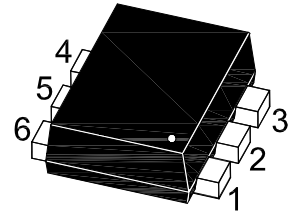
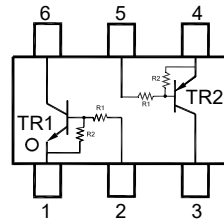


# MMDTX241DE

## Complementary NPN/PNP Silicon Epitaxial Planar Digital Transistors

### Features

- With Built-in bias resistors
- Simplify circuit design



TR1: 1. Emitter 2. Base 6. Collector  
TR2: 4. Emitter 5. Base 3. Collector  
SOT-563 Plastic package

### Resistor Values

R1 (KΩ)	R2 (KΩ)
22	22

### Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$ (TR1)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$V_{CBO}$	50	V
Collector Emitter Voltage	$V_{CEO}$	50	V
Emitter Base Voltage	$V_{EBO}$	6	V
Input Voltage	$V_{IN}$	40 to - 10	V
Collector Current	$I_c$	100	mA

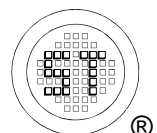
### Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$ (TR2)

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	50	V
Collector Emitter Voltage	$-V_{CEO}$	50	V
Emitter Base Voltage	$-V_{EBO}$	6	V
Input Voltage	$V_{IN}$	- 40 to 10	V
Collector Current	$-I_c$	100	mA

### Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$ (TR1 and TR2)

Parameter	Symbol	Value	Unit
Total Power Dissipation <sup>1)</sup>	$P_{tot}$	500	mW
Thermal Resistance from Junction to Ambient <sup>1)</sup>	$R_{\theta JA}$	250	$^\circ\text{C/W}$
Operating Junction and Storage Temperature Range	$T_j, T_{stg}$	- 55 to + 150	$^\circ\text{C}$

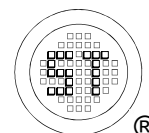
<sup>1)</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.



# MMDTX241DE

## Characteristics at $T_a = 25^\circ\text{C}$ (TR1:NPN)

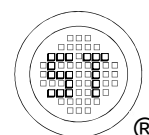
Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_{CE} = 10\text{ V}$ , $I_C = 5\text{ mA}$	$h_{FE}$	60	-	-	-
Collector Base Breakdown Voltage at $I_C = 10\text{ }\mu\text{A}$	$V_{(BR)CBO}$	50	-	-	V
Collector Emitter Breakdown Voltage at $I_C = 2\text{ mA}$	$V_{(BR)CEO}$	50	-	-	V
Collector Base Cut-off Current at $V_{CB} = 50\text{ V}$	$I_{CBO}$	-	-	100	nA
Collector Emitter Cut-off Current at $V_{CE} = 50\text{ V}$	$I_{CEO}$	-	-	500	nA
Emitter Base Cutoff Current at $V_{EB} = 6\text{ V}$	$I_{EBO}$	-	-	200	$\mu\text{A}$
Collector Emitter Saturation Voltage at $I_C = 10\text{ mA}$ , $I_B = 0.3\text{ mA}$	$V_{CE(sat)}$	-	-	250	mV
Input on Voltage at $V_{CE} = 0.2\text{ V}$ , $I_C = 5\text{ mA}$	$V_{I(ON)}$	-	1.9	-	V
Input off Voltage at $V_{CE} = 5\text{ V}$ , $I_C = 0.1\text{ mA}$	$V_{I(OFF)}$	-	1.2	-	V
Output on Voltage at $V_{CC} = 5\text{ V}$ , $V_B = 2.5\text{ V}$ , $R_L = 1\text{ K}\Omega$	$V_{OL}$	-	-	0.2	V
Output off Voltage at $V_{CC} = 5\text{ V}$ , $V_B = 0.5\text{ V}$ , $R_L = 1\text{ K}\Omega$	$V_{OH}$	4.9	-	-	V
Input Resistor	R1	15.4	22	28.6	$\text{K}\Omega$
Resistor Ratio	R1/R2	0.8	1	1.2	-



# MMDTX241DE

## Characteristics at $T_a = 25^\circ\text{C}$ (TR2:PNP)

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $-V_{CE} = 10\text{ V}$ , $-I_C = 5\text{ mA}$	$h_{FE}$	60	-	-	-
Collector Base Breakdown Voltage at $-I_C = 10\text{ }\mu\text{A}$	$-V_{(BR)CBO}$	50	-	-	V
Collector Emitter Breakdown Voltage at $-I_C = 2\text{ mA}$	$-V_{(BR)CEO}$	50	-	-	V
Collector Base Cut-off Current at $-V_{CB} = 50\text{ V}$	$-I_{CBO}$	-	-	100	nA
Collector Emitter Cut-off Current at $-V_{CE} = 50\text{ V}$	$-I_{CEO}$	-	-	500	nA
Emitter Base Cutoff Current at $-V_{EB} = 6\text{ V}$	$-I_{EBO}$	-	-	200	$\mu\text{A}$
Collector Emitter Saturation Voltage at $-I_C = 10\text{ mA}$ , $-I_B = 0.3\text{ mA}$	$-V_{CE(sat)}$	-	-	250	mV
Input on Voltage at $-V_{CE} = 0.2\text{ V}$ , $-I_C = 5\text{ mA}$	$-V_{I(ON)}$	-	2	-	V
Input off Voltage at $-V_{CE} = 5\text{ V}$ , $-I_C = 0.1\text{ mA}$	$-V_{I(OFF)}$	-	1.2	-	V
Output on Voltage at $-V_{CC} = 5\text{ V}$ , $-V_B = 2.5\text{ V}$ , $R_L = 1\text{ K}\Omega$	$-V_{OL}$	-	-	0.2	V
Output off Voltage at $-V_{CC} = 5\text{ V}$ , $-V_B = 0.5\text{ V}$ , $R_L = 1\text{ K}\Omega$	$-V_{OH}$	4.9	-	-	V
Input Resistor	R1	15.4	22	28.6	K $\Omega$
Resistor Ratio	R1/R2	0.8	1	1.2	-



## Electrical Characteristics Curves(TR1 NPN)

Fig 1.  $V_{I(ON)}$  vs. Collector Current

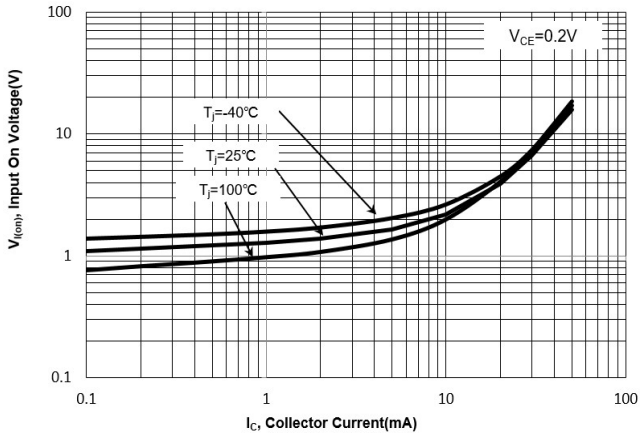


Fig 2.  $V_{I(off)}$  vs. Collector Current

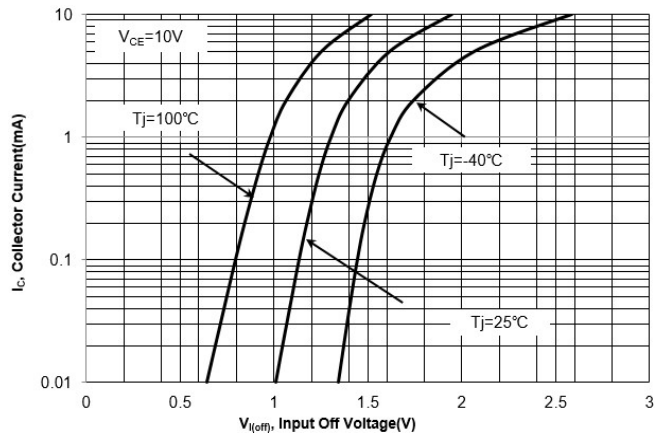


Fig 3. DC Current Gain vs. Collector Current

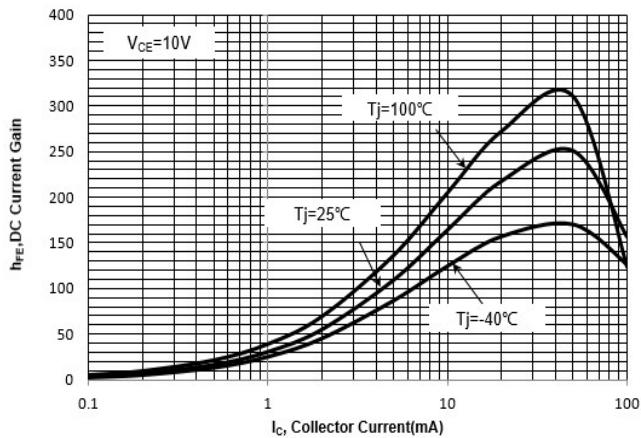
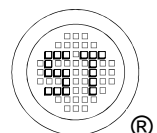
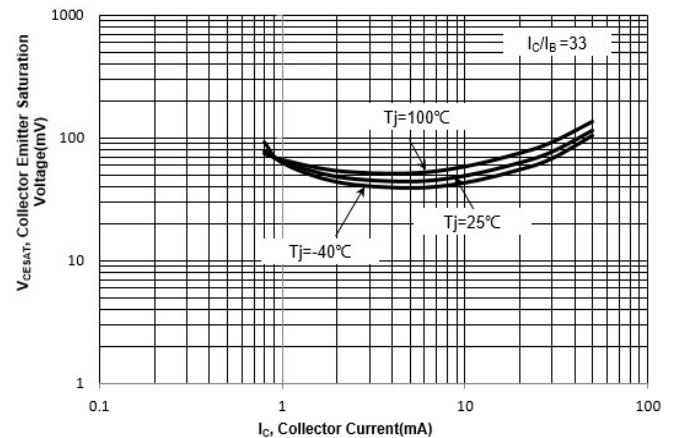


Fig 4.  $V_{CE(sat)}$  vs. Collector Current



## Electrical Characteristics Curves(TR2 PNP)

Fig 1.  $V_{I(ON)}$  vs. Collector Current

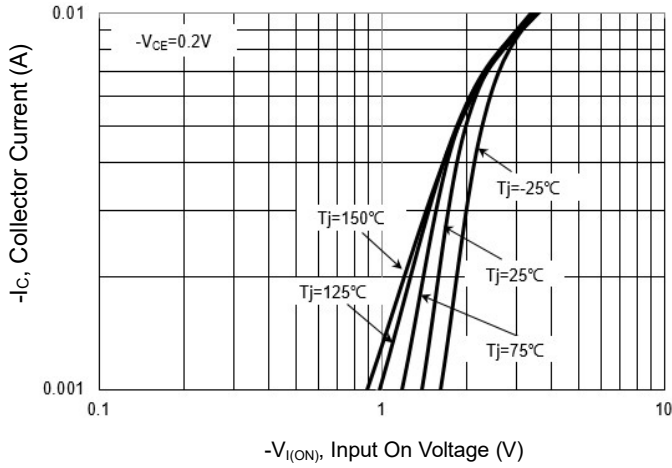


Fig 2.  $V_{I(off)}$  vs. Collector Current

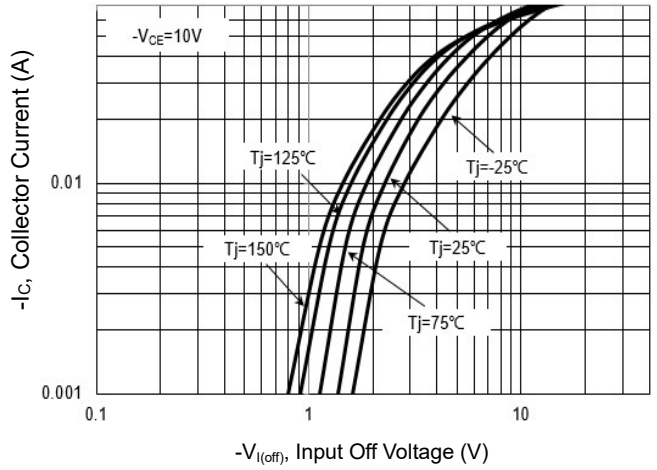


Fig 3. DC Current Gain vs. Collector Current

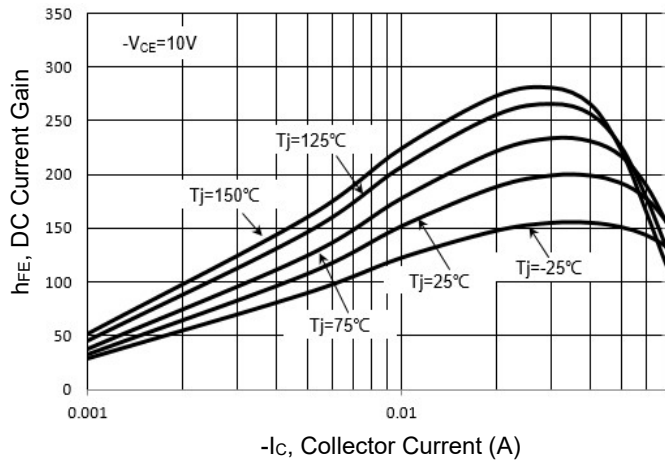
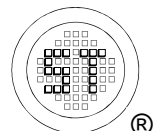
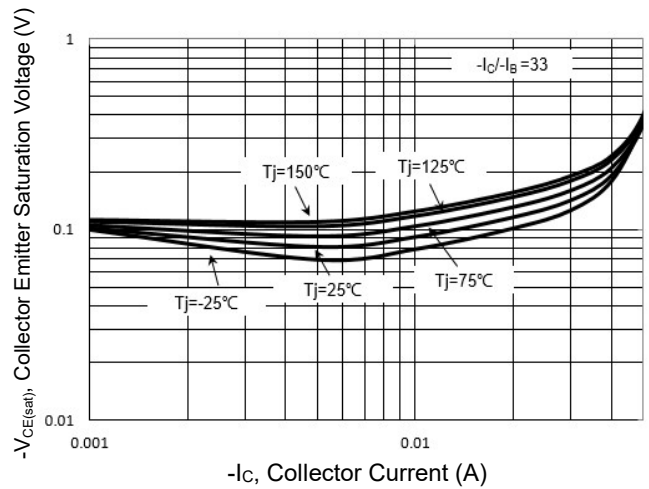


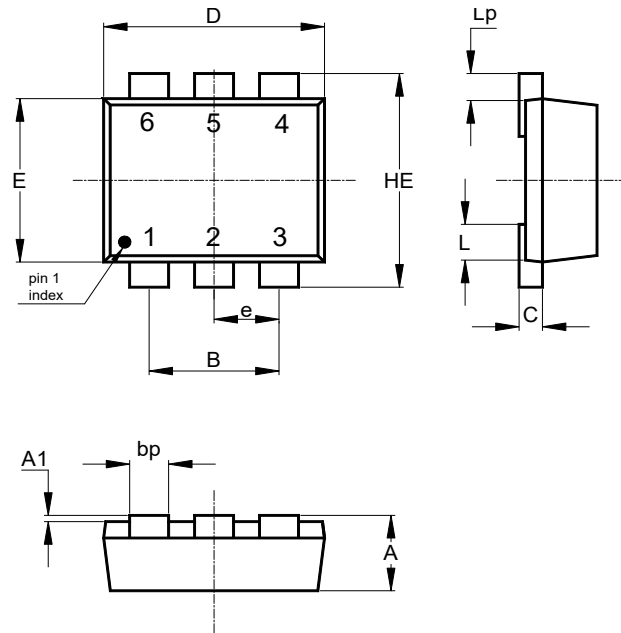
Fig 4.  $V_{CE(sat)}$  vs. Collector Current



# MMDTX241DE

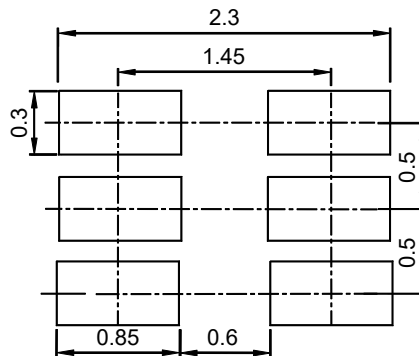
## Package Outline (Dimensions in mm)

SOT-563



Unit	A	A1	B	C	D	E	HE	e	L	Lp	bp
mm	0.6	0.05	1.0	0.18	1.7	1.25	1.7	0.5	0.15	0.3	0.3
	0.5	0	typ.	0.1	1.5	1.1	1.55	Typ.	0.02	0.1	0.15

## Recommended Soldering Footprint



## Packing information

Package	Tape Width (mm)	Pitch		Reel Size		Per Reel Packing Quantity
		mm	inch	mm	inch	
SOT-563	8	4 ± 0.1	0.157 ± 0.004	178	7	4,000

## Marking information

- "SB" = Part No.
  - "YM" = Date Code Marking
  - "Y" = Year
  - "M" = Month
- Font type: Arial

